

# isc N-Channel MOSFET Transistor

# IPP80N08S4-06

### **DESCRIPTION**

- Drain Current I<sub>D</sub>= 80A@ T<sub>C</sub>=25℃
- Drain Source Voltage- V<sub>DSS</sub>=80V(Min)
- · Fast Switching Speed
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **APPLICATIONS**

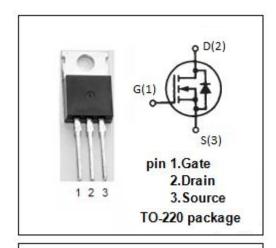
- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- · High current switching applications
- DC-DC converter and motor drive applications

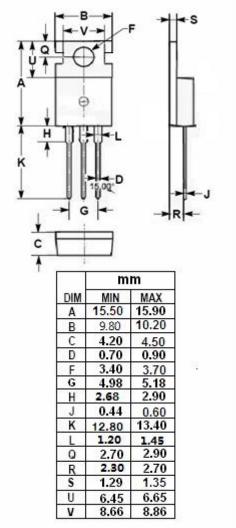
### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	ARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage (V <sub>GS</sub> =0)	80	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-continuous@ T <sub>C</sub> =25℃	80	Α
I <sub>DM</sub>	Drain Current-Single Pluse	320	Α
P <sub>tot</sub>	Total Dissipation@T <sub>C</sub> =25℃	150	W
Tj	Max. Operating Junction Temperature 150		$^{\circ}$
T <sub>stg</sub>	Storage Temperature Range	-55~150	$^{\circ}$

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT				
R <sub>th j-c</sub>	Thermal Resistance,Junction to Case	0.833	°C/W				





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### • ELECTRICAL CHARACTERISTICS (T<sub>C</sub>=25°C)

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0; I <sub>D</sub> = 1mA	80	-	V
V <sub>GS(TH)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250μA	2.0	4.0	V
R <sub>DS(ON)</sub>	Drain-Source On-stage Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 80A	-	5.8	mΩ
I <sub>GSS</sub>	Gate Source Leakage Current	V <sub>GS</sub> = ±20V; V <sub>DS</sub> = 0	-	±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 80V, V <sub>GS</sub> = 0V, T <sub>J</sub> = 25°C	-	1	μA
$V_{SD}$	Diode Forward Voltage	I <sub>S</sub> =80A; V <sub>GS</sub> =0V	-	1.3	V



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